NSN 5961-00-342-3929

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-342-3929 **Inclosure Material:** Metal **Overall Length:** 0.240 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-18 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 30.0 drain to gate voltage all transistor and 30.0 drain to source voltage all transistor **Current Rating Per Characteristic:** 0.10 milliamperes gate current all transistor **Power Rating Per Characteristic:** 0.5 watts total device dissipation all transistor **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0